
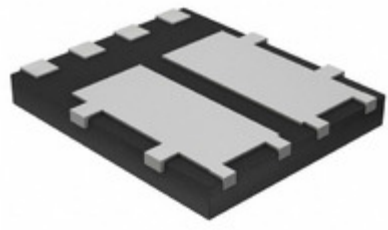
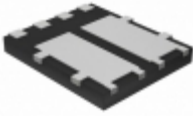
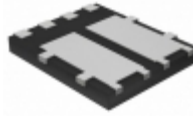
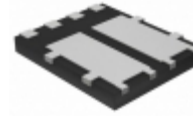
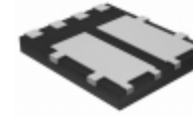
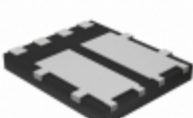
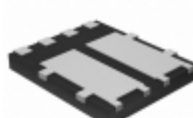
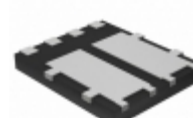
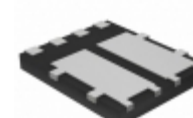
	<h2 style="color: red;">NVMFD5853NLT1G</h2>
	<p>Hersteller-Teilenummer: NVMFD5853NLT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET 2N-CH 40V 12A SO8FL</p> <p>Datenblätter:  NVMFD5853NLT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFD5853NLT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 40V 12A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1500 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3W
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-DFN (5x6) Dual Flag (SO8FL-Dual-Asymmetrical)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A
Rds On (Max) @ Id, Vgs	10 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	2.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1100pF @ 25V
Verpackung	Tape & Reel (TR)














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Sie können auch interessiert sein:

 <p>NVMFD5852NLT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 15A SO8FL</p>	 <p>NVMFD5853NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p>	 <p>NVMFD5873NLT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 10A SO8FL</p>	 <p>NVMFD5489NLWFT3G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 4.5A DFN8</p>
 <p>NVMFD5489NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 4.5A DFN8</p>	 <p>NVMFD5489NLT3G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 4.5A DFN8</p>	 <p>NVMFD5853NT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p>	 <p>NVMFD5873NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 10A SO8FL</p>

heiße Teile

Mehr

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 GA355QR7GF332KW01L	 GRM1535C1H150JDD5D	 GRM2165C1HR80CD01D	 IDT71321LA35J	 IRF6712STR1PBF
 IRFB1104	 IRS2608DSPBF	 KCM55TR7YA226MH01K	 LCA127LS	 LTC2415-1CGN#PBF
 LTC485CN8#PBF	 M29W400DT70N6E	 MIC3775-2.5YMM	 MRF9135LSR3	 NDC7002N-NL
 NE1617DS	 NSS40301MZ4T3G	 NTP45N06L	 NVMD3P03	 NVMD3P03R2G
 NVMD4N03	 NVMD6N04	 NVMFD5877NLT3G	 NVMFD5877NLWFT1G	 NVMFS4C01NWFT1G
 NVMFS4C05N	 NVMFS5113PLT1G	 NVMFS5830NLWFT1G	 NVMFS5885NLT3G	 NVMFS5C450NT1G
 NVMFS5C456NLT1G	 NVMFS5C468NLT1G	 S1AFG-M3/6A	 SA2468AM	 SKIIP31NAB12T3
 ST180C20C0	 T1210-800G-TR	 T3801N18TOF	 TLE4935L	 XC2S300E-6FGG456C

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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